

MAGX-100027-300C0P

Rev. V2

Features

- Suitable for Linear and Saturated Applications
- Pair of Isolated, Symmetric Amplifiers
- CW and Pulsed Operation: 300 W Output Power
- Internally Pre-Matched
- 260°C Reflow Compatible
- 50 V Operation
- 100% RF Tested
- RoHS* Compliant

Description

The MAGX-100027-300C0P is high power GaN on Si HEMT device optimized for DC - 2.7 GHz frequency operation. The device supports both CW and pulsed operation with peak output power levels of 300 W (54.8 dBm) in a plastic package.

The MAGX-100027-300C0P is ideally suited for a multitude of applications including military radio communications, digital cellular infrastructure, RF energy, avionics, test instrumentation and RADAR.

Typical Performance:

• $V_{DS} = 50 \text{ V}, I_{DQ} = 100 \text{ mA}, T_C = 25^{\circ}\text{C}$. One side Measured under pulsed load-pull at 2.5 dB Compression, 100 µs pulse width,1 ms period, 10% duty cycle

| Frequency (GHz) | Output Power ¹ (dBm) | Gain ² (dB) | η ₀ ² (%) |
|--------------------|------------------------------------|---------------------------|-------------------------|
| 0.9 | 53.5 | 20.0 | 71.1 |
| 1.4 | 53.3 | 17.6 | 74.8 |
| 2.0 | 53.5 | 15.0 | 64.3 |
| 2.5 | 53.5 | 13.5 | 64.8 |
| 2.7 | 53.4 | 13.5 | 65.3 |

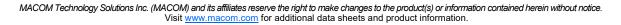
1. Load impedance tuned for maximum output power.

Load impedance tuned for maximum drain efficiency.

Ordering Information

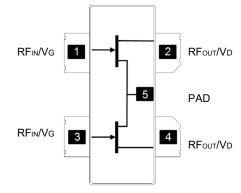
| Part Number | Package |
|--------------------|---------------|
| MAGX-100027-300C0P | Bulk quantity |
| MAGX-100027-300CTP | Tape and Reel |
| MAGX-1A0027-300C0P | Sample board |

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.





Functional Schematic



Pin Configuration

| Pin # | Pin Name | Function |
|-------|---|-------------------|
| 1 | RF _{IN} / V _{G1} | RF Input / Gate |
| 2 | RF _{OUT} / V _{D1} | RF Output / Drain |
| 3 | $\mathrm{RF}_{\mathrm{IN}}$ / V_{G2} | RF Input / Gate |
| 4 | $\mathrm{RF}_{\mathrm{OUT}}$ / V_{D2} | RF Output / Drain |
| 5 | Pad ³ | Ground / Source |

3. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.



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RF Electrical Characteristics: $T_c = 25^{\circ}C$, $V_{DS} = 50 V$, $I_{DQ} = 200 mA$ Note: Performance in MACOM Evaluation Test Fixture, 50 Ω system

| Parameter | Test Conditions | Symbol | Min. | Тур. | Max. | Units |
|----------------------------------|---|---------------------|------|----------|------|-------|
| Small Signal Gain | Pulsed ⁴ , 2 GHz | G _{SS} | - | 16.3 | - | dB |
| Power Gain | Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression | G _{SAT} | - | 14.0 | - | dBm |
| Saturated Drain Efficiency | Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression | η_{SAT} | - | 57.5 | - | % |
| Saturated Output Power | Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression | P _{SAT} | - | 55.5 | - | dBm |
| Gain Variation (-25°C to +85°C) | Pulsed ⁴ , 2 GHz | ΔG | - | 0.02 | - | dB/∘C |
| Power Variation (-25°C to +85°C) | Pulsed ⁴ , 2 GHz | $\Delta P2.5 dB$ | - | 0.01 | - | dB/∘C |
| Gain | Pulsed ⁴ , 2 GHz, P _{IN} = 41.2 dBm | G _P | - | 14.5 | - | dB |
| Drain Efficiency | Pulsed ⁴ , 2.0 GHz, P _{IN} = 41.2 dBm | η | - | 57.5 | - | % |
| Ruggedness: Output Mismatch | All phase angles | Ψ VSWR = 10:1, No E | | l, No Da | mage | |

RF Electrical Specifications: $T_A = 25^{\circ}C$, $V_{DS} = 50$ V, $I_{DQ} = 200$ mA Note: Performance in MACOM Production Test Fixture, 50 Ω system

| Parameter | Test Conditions | Symbol | Min. | Тур. | Max. | Units |
|----------------------------|--|------------------|------|------|------|-------|
| Power Gain | Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression | G _{SAT} | 13 | 14 | - | dB |
| Saturated Drain Efficiency | Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression | η_{SAT} | 52 | 57.5 | - | % |
| Saturated Output Power | Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression | P _{SAT} | 54 | 55.4 | - | dBm |
| Gain | Pulsed ⁴ , 2 GHz, P_{IN} = 41.2 dBm | G _P | 13 | 14.2 | - | dB |
| Drain Efficiency | Pulsed ⁴ , 2 GHz, P_{IN} = 41.2 dBm | η | 52 | 57.5 | - | dB |

4. Pulse details: 100 µs pulse width, 1 ms period, 10% Duty Cycle.

DC Electrical Characteristics (Per Each Side of Symmetric Device) T_A = 25°C

| Parameter | Test Conditions | Symbol | Min. | Тур. | Max. | Units |
|------------------------------|--|---------------------|------|-------|------|-------|
| Drain-Source Leakage Current | V _{GS} = -8 V, V _{DS} = 130 V | | - | - | 29.2 | mA |
| Gate-Source Leakage Current | V_{GS} = -8 V, V_{DS} = 0 V | I _{GLK} | - | - | 29.2 | mA |
| Gate Threshold Voltage | V _{DS} = 50 V, I _D = 29.2 mA | VT | -2.6 | -2.15 | -1.6 | V |
| Gate Quiescent Voltage | V _{DS} = 50 V, I _D = 150 mA | V_{GSQ} | -2.4 | -2.05 | -1.4 | V |
| On Resistance | V _{GS} = 2 V, I _D = 200 mA | R _{ON} | - | 0.16 | - | Ω |
| Maximum Drain Current | V_{DS} = 7 V pulsed, pulse width 300 µs | I _{D, MAX} | - | 17.0 | - | Α |

²

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Absolute Maximum Ratings (Per Each Side of Symmetric Device)^{5,6,7,8,9}

| Parameter | Absolute Maximum |
|--|------------------|
| Drain Source Voltage, V _{DS} | 130 V |
| Gate Source Voltage, V _{GS} | -10 to 3 V |
| Gate Current, I _G | 29 mA |
| Storage Temperature Range | -65°C to +150°C |
| Case Operating Temperature Range | -40°C to +85°C |
| Channel Operating Temperature Range, T _{CH} | -40°C to +225°C |
| Absolute Maximum Channel Temperature | +250°C |

5. Exceeding any one or combination of these limits may cause permanent damage to this device.

MACOM does not recommend sustained operation above maximum operating conditions. 6.

7.

8.

Operating at drain source voltage $V_{DS} < 55$ V will ensure MTTF > 1 x 10⁷ hours. Operating at nominal conditions with $T_{CH} \le 225^{\circ}$ C will ensure MTTF > 1 x 10⁷ hours. MTTF may be estimated by the expression MTTF (hours) = A $e^{[B + C/(T+273)]}$ where *T* is the channel temperature in degrees Celsius, 9 A = 3.686, B = -35.00, and C = 25,416.

Thermal Characteristics¹⁰

| Parameter | Test Conditions | Symbol | Typical | Units |
|---|---|---------------------|---------|-------|
| Thermal Resistance using Finite Element Analysis | V _{DS} = 50 V, T _C = 85°C, T _{CH} = 225°C | $R_{\theta}(FEA)$ | 0.56 | °C/W |
| Thermal Resistance using Infrared Measurement of Die Surface Temperature | V _{DS} = 50 V, T _C = 85°C, T _{CH} = 225°C | R _θ (IR) | 0.45 | °C/W |

10. Case temperature measured using thermocouple embedded in heat-sink. Contact local applications support team for more details on this measurement.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Nitride Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM Class 1A, CDM Class C3 devices.

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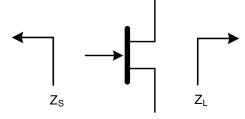


Pulsed⁴ Load-Pull Performance (Per Each Side of Symmetric Device) Reference Plane at Device Leads

| | | Maximum Output Power | | | | | | | |
|--------------------|----------------------------|--|---|---------------------------|-------------------------|-----------|----------------------------|--|--|
| | | | V _{DS} = 50 V, I _{DQ} = 100 mA, T _C = 25°C, P2.5dB | | | | | | |
| Frequency (GHz) | Z _{SOURCE} (Ω) | Z _{LOAD} ¹¹ (Ω) | Gain (dB) | Р _{оит} (dBm) | Р _{оит} (W) | η₀ (%) | AM/PM ¹³ (°) | | |
| 0.9 | 5 - j2.0 | 3.4 - j0.4 | 19.3 | 53.5 | 222.6 | 58.3 | 0.3 | | |
| 1.4 | 5 - j4.6 | 2.6 - j0.7 | 16.0 | 53.3 | 215.6 | 62.7 | 0.5 | | |
| 2.0 | 5 - j6.3 | 1.8 - j1.8 | 14.4 | 53.5 | 222.6 | 61.3 | -3.4 | | |
| 2.5 | 5 - j11.0 | 1.5 - j3.2 | 12.9 | 53.5 | 222.6 | 60.6 | -6.4 | | |
| 2.7 | 5 - j11.0 | 1.9 - j3.8 | 12.3 | 53.4 | 220.9 | 59.0 | -9.6 | | |

| | | Maximum Drain Efficiency | | | | | | |
|--------------------|----------------------------|---|--------------|---------------------------|-------------------------|-----------|----------------------------|--|
| | | V _{DS} = 50 V, I _{DQ} = 100 mA, T _C = 25°C, P2.5dB | | | | | | |
| Frequency (GHz) | Z _{SOURCE} (Ω) | Z _{LOAD} ¹² (Ω) | Gain (dB) | Р _{оит} (dBm) | Р _{оит} (W) | η₀ (%) | AM/PM ¹³ (°) | |
| 0.9 | 5 - j2.0 | 5.4 + j3.0 | 20.0 | 52.4 | 175.5 | 71.1 | -4.8 | |
| 1.4 | 5 - j4.6 | 2.5 + j1.6 | 17.6 | 51.9 | 154.6 | 74.8 | -3.5 | |
| 2.0 | 5 - j6.3 | 1.8 - j1.1 | 15.0 | 52.9 | 195.2 | 64.3 | -3.8 | |
| 2.5 | 5 - j11.0 | 1.4 - j2.3 | 13.5 | 52.6 | 180.0 | 64.8 | -8.5 | |
| 2.7 | 5 - j11.0 | 1.1 - j2.7 | 13.5 | 51.8 | 148.5 | 65.3 | -17.0 | |

Impedance Reference



 Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane. Z_{LOAD} = Measured impedance presented to the output of the

device at package reference plane.

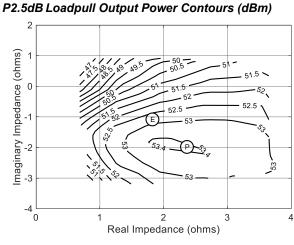
- 11. Load Impedance for optimum output power.
- 12. Load Impedance for optimum efficiency.
- 13. AM/PM are relative values.

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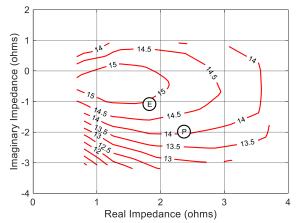


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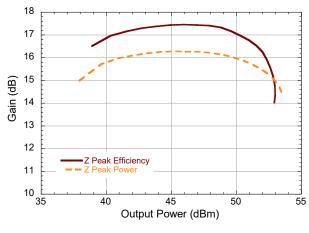
Pulsed⁴ Load-Pull Performance (Per Each Side of Symmetric Device) 2.0 GHz



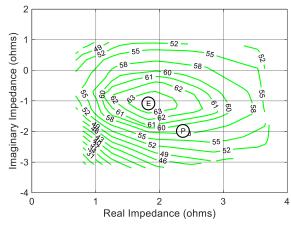
P2.5dB Loadpull Gain Contours (dB)



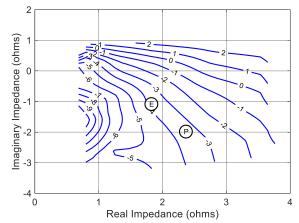
Gain vs. Output Power



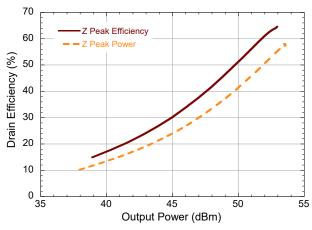
P2.5dB Loadpull Drain Efficiency Contours (%)



P2.5dB Loadpull AM/PM Contours (°)



Drain Efficiency vs. Output Power

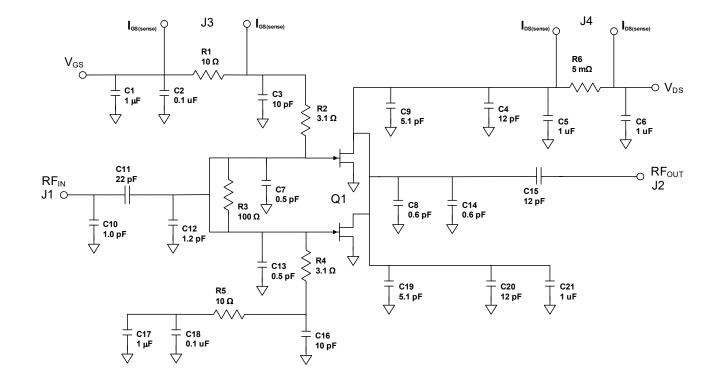


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Evaluation Test Fixture and Recommended Tuning Solution 1.95 - 2.05 GHz

Description

Parts measured on evaluation board (20-mil thick RO4350). Matching is provided using a combination of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

Bias Sequencing Turning the device ON

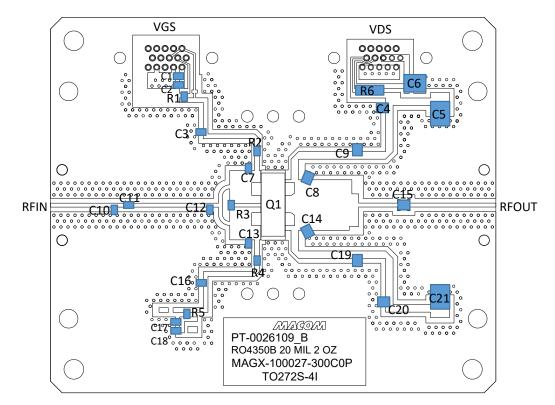
- 1. Set V_{GS} to pinch-off (V_P).
- 2. Turn on V_{DS} to nominal voltage (50 V).
- 3. Increase V_{GS} until I_{DS} current is reached.
- 4. Apply RF power to desired level.

Turning the device OFF

- 1. Turn the RF power off.
- 2. Decrease V_{GS} down to V_P pinch-off.
- 3. Decrease V_{DS} down to 0 V.
- 4. Turn off V_{GS} .

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Evaluation Test Fixture and Recommended Tuning Solution 1.95 - 2.05 GHz

| Reference Designator | Value | Tolerance | Manufacturer | Part Number | |
|----------------------|--------|--|---------------------|--------------------|--|
| C1, C18 | 1.0 µF | +/- 10 % | Murata | GRM21BC72A105KE01L | |
| C2, C17 | 0.1 µF | +/- 10 % | Murata | GCD21BR72A104KA01L | |
| C3, C16 | 10 pF | +/- 0.1 pF | PPI | 0505C100BW151X | |
| C4, C15, C20 | 12 pF | +/- 0.1 pF | PPI | 111N120BW501X | |
| C5, C6, C21 | 1 µF | +/- 10 % | Murata | GRM55DR72E105KW01L | |
| C7, C13 | 0.5 pF | +/- 0.1 pF | PPI | 0505C0R5BW151X | |
| C8, C14 | 0.6 pF | +/- 0.1 pF | PPI | 1111N0R6BW501X | |
| C9, C19 | 5.1 pF | +/- 0.1 pF | PPI | 1111N5R1BW501X | |
| C10 | 1 pF | +/- 0.1 pF | PPI | 0505C1R0BW151X | |
| C11 | 22 pF | +/- 0.1 pF | PPI | 0505C220JW151X | |
| C12 | 1.2 pF | +/- 0.1 pF | PPI | 0505C1R2BW151X | |
| R1, R5 | 10 Ω | +/- 1 % | Vishay Dale | CRCW080510R0FKTA | |
| R2, R4 | 3.1 Ω | +/- 1 % | Vishay Dale | CRCW08053R09FKEA | |
| R3 | 100 Ω | +/- 1 % | Vishay Dale | CRCW0805100RFKEA | |
| R6 | 5 mΩ | +/- 1 % | Susumu | RL7520WT-R005-F | |
| Q1 | MACO | COM GaN Power Amplifier MAGX-100027-300C0P | | | |
| PCB | | RO4350, | 20 mil, 2 oz. Cu, A | u Finish | |

⁷

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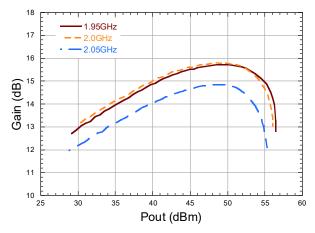


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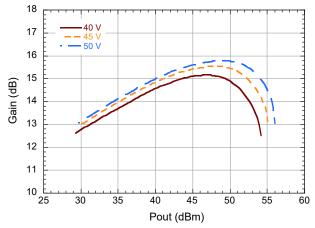
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Typical Performance Curves as Measured in the 1.95 - 2.05 GHz Evaluation Test Fixture: Pulsed⁴ 2.0 GHz, V_{DS} = 50 V, I_{DQ} = 200 mA, T_{C} = 25°C (Unless Otherwise Noted)

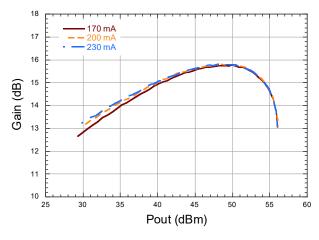
Gain vs. Output Power and Frequency



Gain vs. Output Power and V_{DS}

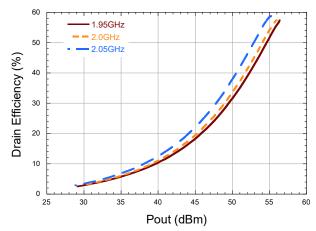


Gain vs. Output Power and IDQ

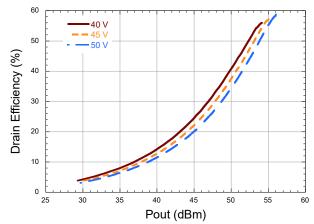


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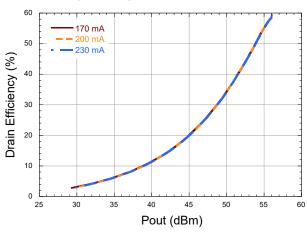
Drain Efficiency vs. Output Power and Frequency



Drain Efficiency vs. Output Power and V_{DS}



Drain Efficiency vs. Output Power and IDQ



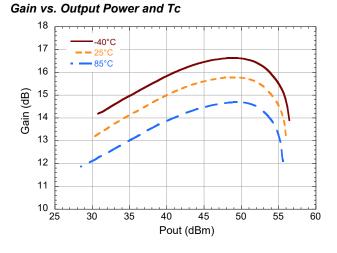
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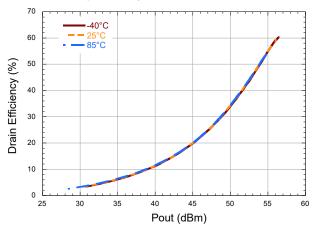
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Typical Performance Curves as Measured in the 1.95 - 2.05 GHz Evaluation Test Fixture: $Pulsed^4 2.0 GHz$, $V_{DS} = 50 V$, $I_{DQ} = 200 mA$, $T_C = 25^{\circ}C$ (Unless Otherwise Noted)



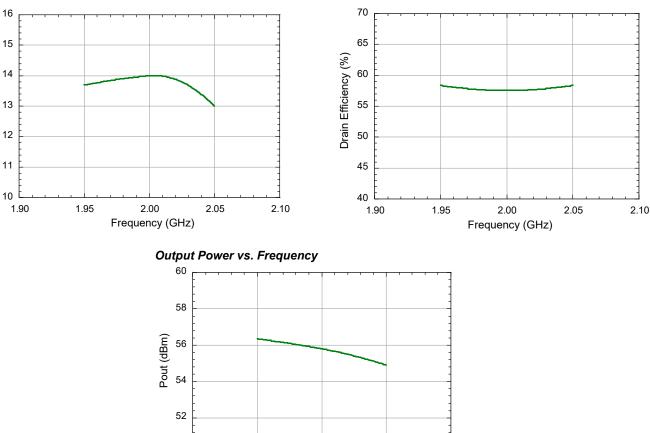
Drain Efficiency vs. Output Power and Tc



Gain vs. Frequency

Gain (dB)

Drain Efficiency vs. Frequency



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2.00 Frequency (GHz) 2.05

2.10

1.95

50

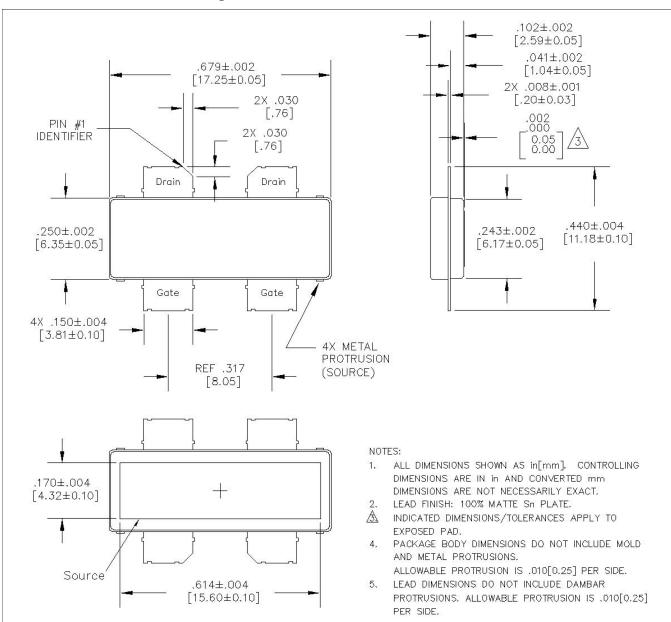
1.90

⁹



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Lead-Free TO-272S-4I Package Dimensions[†]

[†] Reference Application Note AN0004125 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is Matte Sn.

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